Thermal Characteristics

Package	l _D (continuous) [†]	I _D (pulsed)	Power Dissipation @T _c = 25°C	l _{DR} †	I _{DRM}
TO-92	500mA	3.2A	1.0W	500mA	3.2A

Notes:

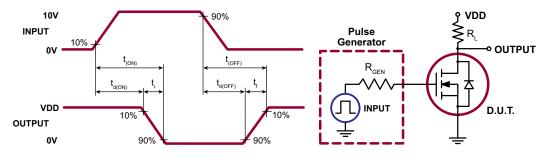
Electrical Characteristics (T_A = 25°C unless otherwise specified)

Sym	Parameter	Min	Тур	Max	Units	Conditions	
BV _{DSS}	Drain-to-source voltage	60	-	-	V	$V_{GS} = 0V, I_D = 1.0mA$	
$V_{GS(th)}$	Gate threshold voltage	0.6	ı	2.0	V	$V_{GS} = V_{DS}$, $I_{D} = 1.0$ mA	
$\Delta V_{\text{GS(th)}}$	Change in V _{GS(th)} with temperature	-	-	-4.5	mV/°C	$V_{GS} = V_{DS}$, $I_D = 1.0 \text{mA}$	
I _{GSS}	Gate body leakage	-	1	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
I _{DSS}	Zero gate voltage drain current		ı	10	μΑ	$V_{GS} = 0V, V_{DS} = Max Rating$	
			ı	1.0	mA	$V_{DS} = 0.8$ Max Rating, $V_{GS} = 0V$, $T_A = 125$ °C	
I _{D(ON)}	On-state drain current	1.2	2.0	-	Α	$V_{GS} = 5.0V, V_{DS} = 25V$	
		3.0	6.7	-		$V_{GS} = 10V, V_{DS} = 25V$	
R _{DS(ON)}	Static drain-to-source on-state resistance	-	-	15	Ω	$V_{GS} = 3.0V, I_{D} = 250mA$	
		-	1.5	2.0		$V_{GS} = 5.0V, I_{D} = 750mA$	
		-	1.0	1.5		$V_{GS} = 10V, I_{D} = 750mA$	
$\Delta R_{DS(ON)}$	Change in R _{DS(ON)} with temperature	-	ı	0.75	%/°C	$V_{GS} = 10V, I_{D} = 750mA$	
G _{FS}	Forward transductance	400	500	-	mmho	$V_{DS} = 25V, I_{D} = 1.0A$	
C _{ISS}	Input capacitance	-	100	150		V _{GS} = 0V, V _{DS} = 25V, f = 1.0MHz	
C _{oss}	Common source output capacitance	-	50	85	pF		
C _{RSS}	Reverse transfer capacitance	-	10	35			
t _{d(ON)}	Turn-on delay time	-	-	6		$V_{DD} = 25V,$ $I_{D} = 1.5A,$ $R_{GEN} = 25\Omega$	
t _r	Rise time	-	-	14	ns		
t _{d(OFF)}	Turn-off delay time	-	-	16	113		
t _f	Fall time	-	-	16			
V _{SD}	Diode forward voltage drop	-	0.8	1.8	V	$V_{GS} = 0V, I_{SD} = 1.5A$	
t _{rr}	Reverse recovery time	-	300	-	ns	$V_{GS} = 0V$, $I_{SD} = 1.5A$	

Notes:

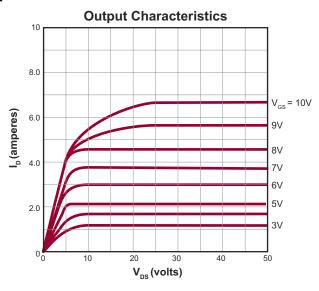
- 1. All D.C. parameters 100% tested at 25°C unless otherwise stated. (Pulse test: 300µs pulse, 2% duty cycle.)
- 2. All A.C. parameters sample tested.

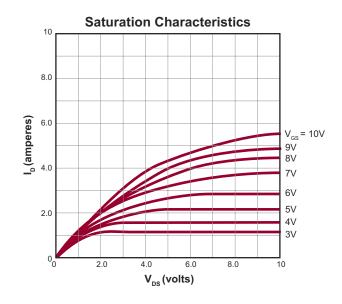
Switching Waveforms and Test Circuit

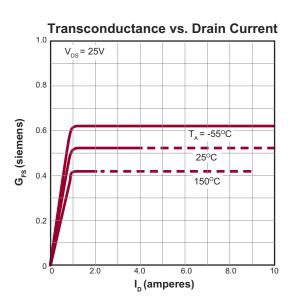


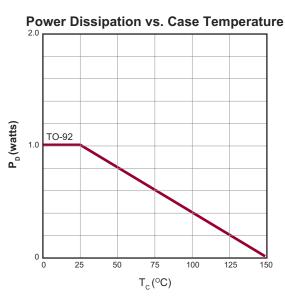
[†] I_D (continuous) is limited by max rated T_i .

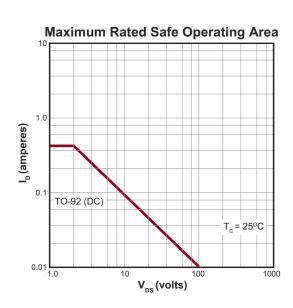
Typical Performance Curves

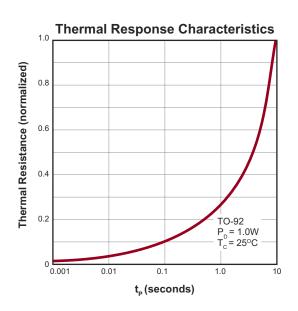




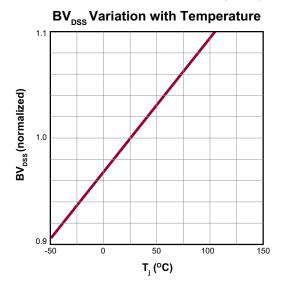


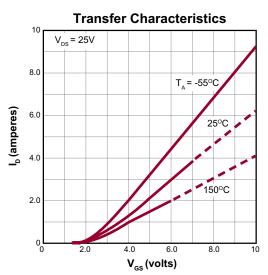


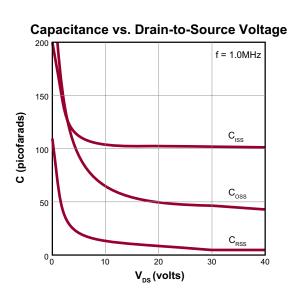


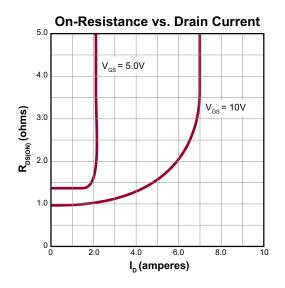


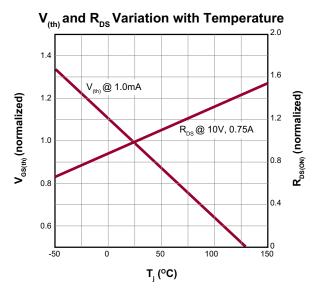
Typical Performance Curves (cont.)

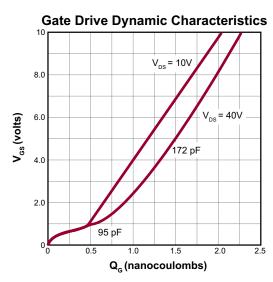




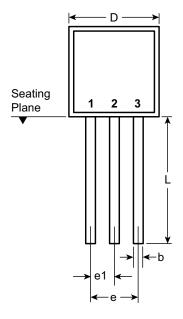


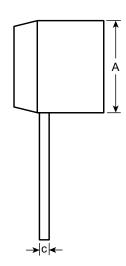






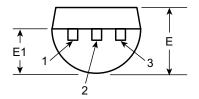
3-Lead TO-92 Package Outline (N3)





Front View

Side View



Bottom View

Symbol		Α	b	С	D	E	E1	е	e1	L
Dimensions (inches)	MIN	.170	.014 [†]	.014 [†]	.175	.125	.080	.095	.045	.500
	NOM	-	-	-	-	-	-	-	-	-
	MAX	.210	.022 [†]	.022 [†]	.205	.165	.105	.105	.055	.610*

JEDEC Registration TO-92.

Drawings not to scale.

Supertex Doc.#: DSPD-3TO92N3, Version E041009.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to http://www.supertex.com/packaging.html.)

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^{*} This dimension is not specified in the JEDEC drawing.

[†] This dimension differs from the JEDEC drawing.